

**A General Strategy to Prepare High-quality Inorganic Charge-transporting
Layers for Efficient and Stable All-layer-inorganic Perovskite Solar Cells**

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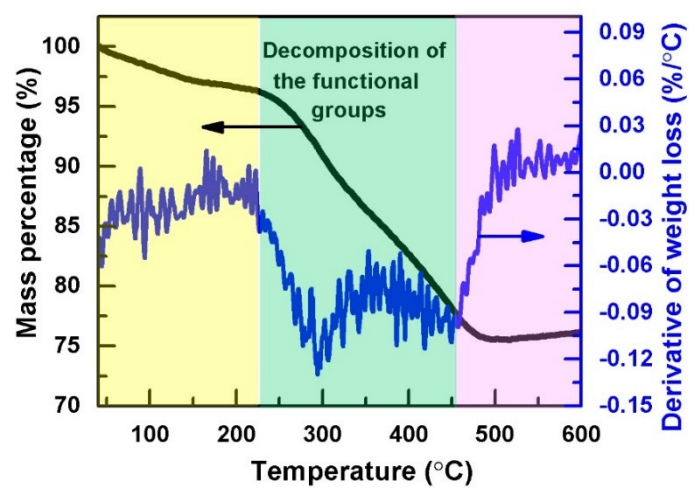


Fig. S1. Thermogravimetry in N_2 of the OA-capped NCs.

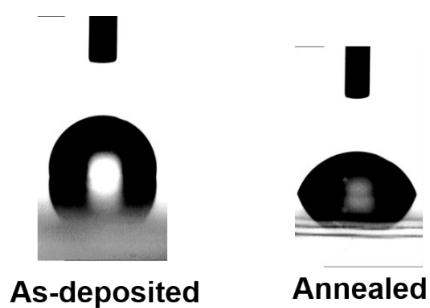


Fig. S2. The moist angles of OA-capped In_2O_3 NCs before and after annealing at 250 $^{\circ}C$.

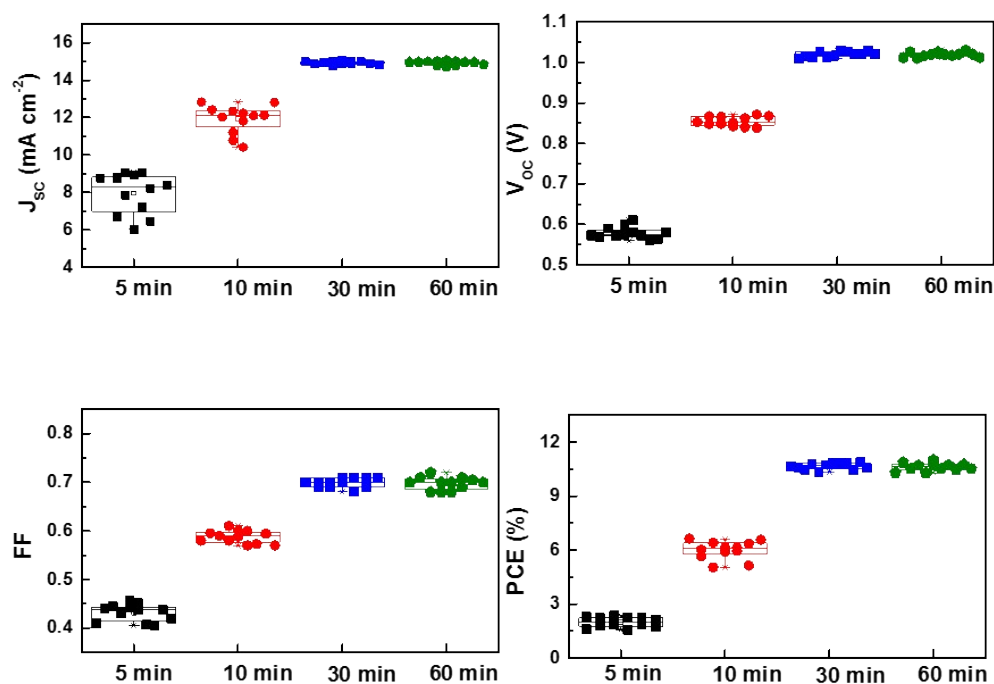


Fig. S3. Statistic photovoltaic parameters of devices with C-In₂O₃ ETLs annealed for different times.

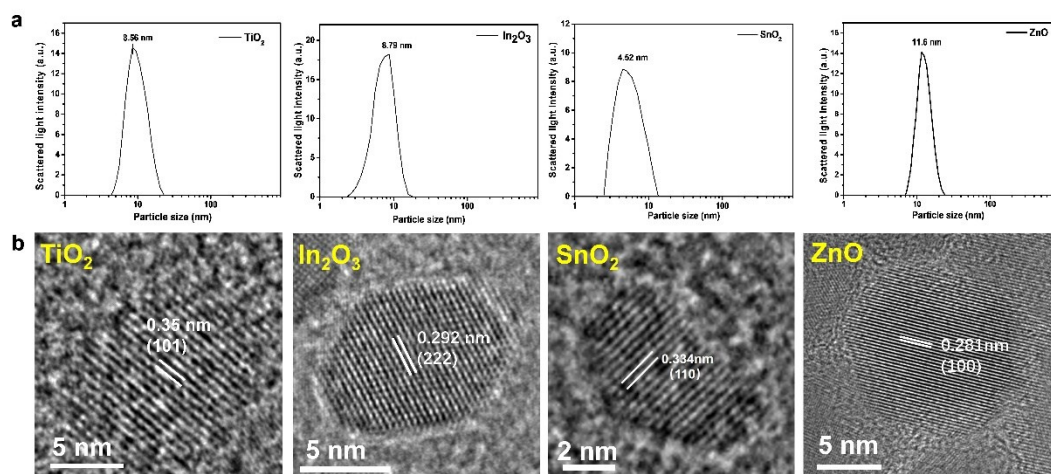


Fig. S4. (a) Dynamic light scattering and (b) high-resolution TEM images of the OA coated MOX NCs.

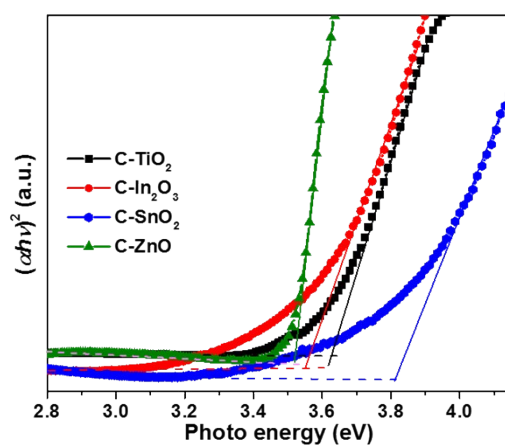


Fig. S5. UV-vis absorption of different C-MOX films.

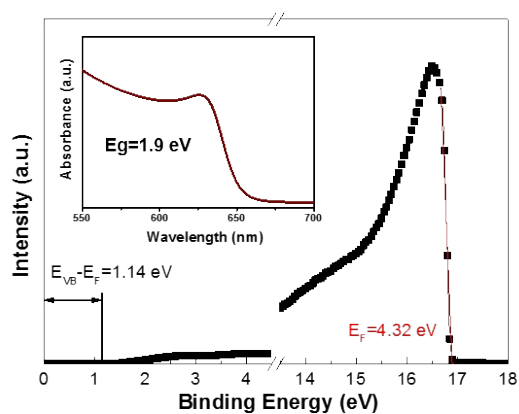


Fig. S6. UPS and the UV-vis absorption of CsPbI₂Br films, from which the band structure can be extracted.

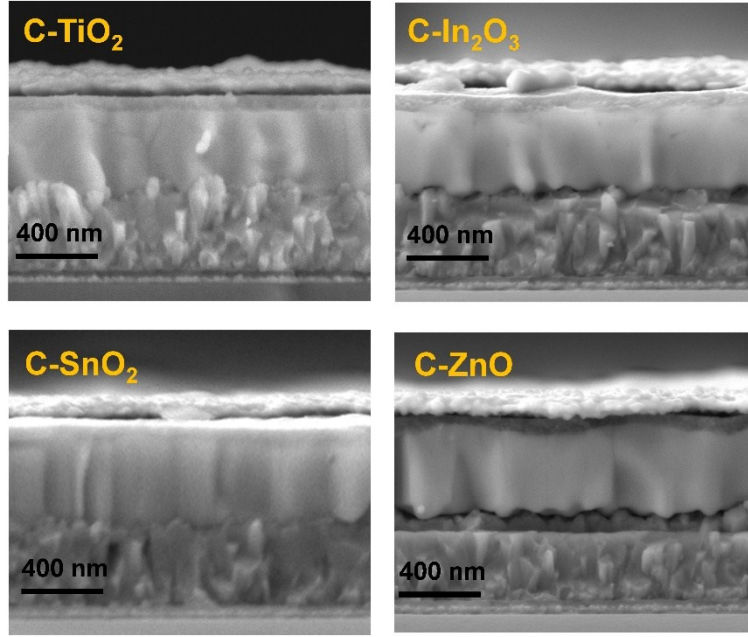


Fig. S7. The cross-sectional SEM images of all-layer-inorganic PSCs with the structure FTO/NiMgLiO/CsPbI₂Br/C-MOX/Ag.

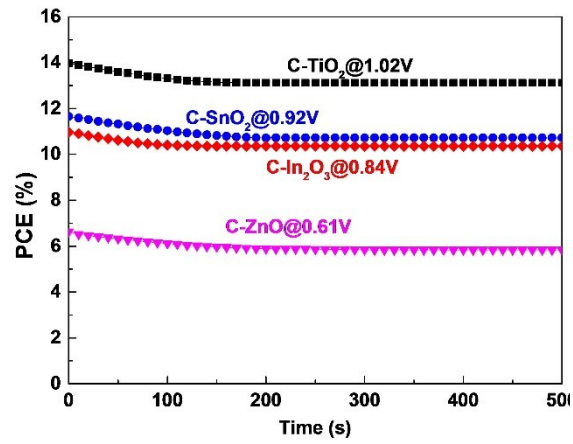


Fig. S8. The stabilized power output data (SPO) of devices based on different ETLs.

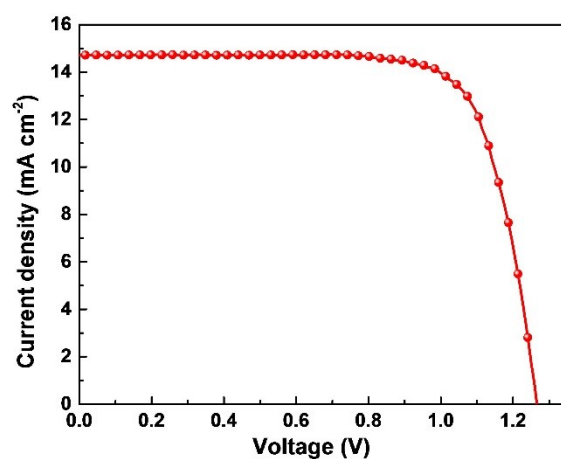


Fig. S9. J - V curve of the champion device with the C-TiO₂ as the ETL.

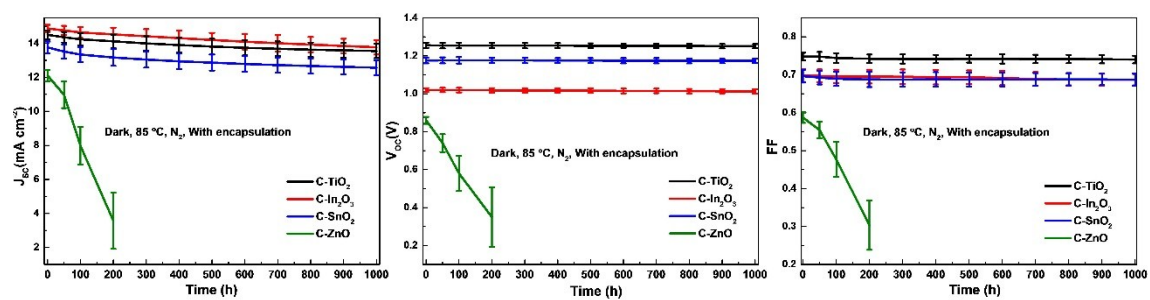


Fig. S10. Changes of photovoltaic parameters of encapsulated devices with different ETLs aged at 85 °C in the dark in a glovebox containing an inert N₂ atmosphere.

Table S1. Summary of the champion PCE and stability of CsPbI₂Br and other cesium lead halide-based devices.

Perovskite absorber	Device structure	PCE		Stability				Reference
		(%)	Decline	Dark/Light	Temperature	Atmosphere	Encapsulation	
CsPbI ₂ Br	FTO/TiO ₂ /CsPbI ₂ Br/P3HT/Au	12.02	10% for 960 h	Dark	/	dried glovebox	Without	Adv. Mater. 2018, 1705393
CsPbI ₂ Br	FTO/c-TiO ₂ /m-TiO ₂ /CsPbI ₂ Br/spiro-OMeTAD/Ag	12.5	No drop for 500 h	Dark	25 °C	Ambient (RH < 25%)	Without	J. Phys. Chem. Lett. 2018, 9, 3646–3653
CsPbI ₂ Br	FTO/c-TiO ₂ /CsPbI ₂ Br/spiro-OMeTAD/Ag	10.56	9% for 35 days	Dark	25–30 °C	Dry box RH=15–20%	Without	Sol. RRL 2018, 2, 1700180
3D–2D–0D CsPbI ₂ Br	FTO/TiO ₂ /CsPbI ₂ Br/PTAA/Au	12.39	No drop for 60 days	Dark	25 °C	RH=25–35%	Without	Adv. Energy Mater. 2018, 1703246
Mn ²⁺ doped CsPbI ₂ Br+ QDs	FTO/TiO ₂ /CsPbI ₂ Br/CsPbI ₂ Br QDs/PTAA/Au	13.47	3% for 35 days	Dark	25 °C	RH=25–35%	Without	ACS Energy Lett. 2018, 3, 970–978
CsPbI ₂ Br	FTO/TiO ₂ /CsPbI ₂ Br/spiro-OMeTAD/Au	14.78	No drop for 500 h	Dark	25 °C	Ambient (RH ~ 20%)	Without	Adv. Funct. Mater. 2018, 28, 1803269
CsPbI ₂ Br+ Mn ²⁺ doped CsPbI ₃ QDs	FTO/TiO ₂ /CsPbI ₂ Br/CsPbI ₃ QDs/PTAA/Au	14.45	<10% for 20 days	Dark	/	N ₂	Without	Joule 2, 1–11, August 15, 2018
CsPb _{0.98} Sr _{0.02} I ₂ Br	FTO/c-TiO ₂ /m-TiO ₂ /CsPb _{1-x} Sr _x I ₂ Br/P3HT/Au	11.3	No drop for 30 days	Dark	25 °C	RH<50 %	With	ACS Energy Lett. 2017, 2, 2319–2325
CsPbI ₂ Br	ITO/Ca/C60/CsPbI ₂ Br/TAPC/TAPC:MoO ₃ /Ag	11.8	4% for 66 days	Dark	25 °C	/	With	Adv. Mater. 2017, 29, 1605290
CsPbI ₂ Br	ITO/SnO ₂ /ZnO/CsPbI ₂ Br/Spiro-	14.6	20% for 300 h	Dark	85 °C	N ₂	Without	Adv. Mater. 2018,

	OMeTAD/MoO ₃ /Ag							1802509
CsPbI ₂ Br	FTO/NiO _x /CsPbI ₂ Br/ ZnO@C60/Au (inverted)	~13	20% for 360 h	Dark	85 °C	N ₂	Without	J. Am. Chem. Soc. 2018, 140, 3825
CsPbI ₂ Br	FTO/TiO ₂ /CsPbI ₂ Br/s piro-OMeTAD/Au	9.3	<1% for 1500 h	Light (UV filter)	25 °C	N ₂	/	J. Phys. Chem. Lett. 2017, 8, 4122–4128
CsPbI ₂ Br	ITO/Ca/C60/CsPbI ₂ B r/TAPC/TAPC:MoO 3/Ag (inverted)	11.8	20% for 120 h	Light (UV filter)	25 °C	ambien t	With	Adv. Mater. 2017, 29, 1605290
CsPbI ₂ Br	ITO/c- TiO ₂ /CsPbI ₂ Br/spiro- OMeTAD/Au	16.07	<10% for 120 h	Light	25 °C	N ₂	Without	Joule 2019, 3, 1–14
CsPbI ₂ Br	ITO/SnO ₂ /PN4N/PVSC/PDCB T/MoO ₃ /Ag	16.2	<10% for 400 h	Light	25 °C	N ₂	Without	Adv. Mater. 2019, 1901152
CsPbI ₂ Br	FTO/NiMgLiO/CsP bI ₂ Br/C-TiO ₂ /Bi/Ag (inverted)	13.84	8% for 1000 h	Dark	85 °C	N ₂	With	This work
CsPbI ₂ Br	FTO/NiMgLiO/CsP bI ₂ Br/C-TiO ₂ / Bi/Ag (inverted)	13.88	5% for 1000 h	Light (UV filter)	45 °C	N ₂	With	This work
CsPbI ₃	FTO/PTAA/CsPbI ₃ (OTG)/PCBM/BCP/ Ag (inverted)	13.32	~15% for 30 days	Dark	25 °C	RH <10%	Without	Adv. Mater. 2019, 1900605
CsPb _{0.9} Sn _{0.1} I Br ₂	FTO/c-TiO ₂ /m- TiO ₂ /CsPb _{0.9} Sn _{0.1} IBr ₂ /carbon	11.3	No drop for 14 days	Dark	100 °C	/	With	J. Am. Chem. Soc. 2017, 139, 14009–140 12
CsPbBr ₃	FTO/c-TiO ₂ /m- TiO ₂ /GQDs/CsPbBr ₃ / carbon	9.7	No drop for 40 days	Dark	80 °C	RH=0%	/	Angew. Chem. Int. Ed. 2018, 57, 3787 – 3791